

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION OF

YAMADA et al

Group Art Unit: 2812

Appln. No.: 09/993,967

Examiner:

Filed: November 27, 2001

Atty Dkt 44020/284032
C# M#

Title: SEMICONDUCTOR DEVICE AND
METHOD OF FABRICATING THE SAME



Date: February 11, 2002

* * * * *

INFORMATION DISCLOSURE STATEMENT

Attached is Form PTO-1449 listing the enclosed:

Contingent Request Under Rule 97(c): Should a first action on the merits have been issued on the same day or before this Information Disclosure Statement is filed, please accept this Information Disclosure Statement under Rule 97(c) and charge the requisite Rule 17(p) fee to our Deposit Account No. 03-3975, under the above Atty Dkt. No., and proceed to consider this Information Disclosure Statement.

This IDS is intended to be in full compliance with the rules, but should the Examiner find any part of its required content to have been omitted, prompt notice to that effect is earnestly solicited, along with additional time under Rule 97(f), to enable Applicant to comply fully.

Consideration of the foregoing and enclosures plus the return of a copy of the enclosed Form PTO-1449 with the Examiner's initials in the left column per MPEP 609 are earnestly solicited along with an early action on the merits.

Respectfully submitted,

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Client Ref.

284032

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**INFORMATION DISCLOSURE STATEMENT
BY APPLICANT**



Applicant: YAMADA et al

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Page 1 of 1

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U.S. PATENT DOCUMENTS

Examiner's Initials*	Document Number	Date MM/YYYY	Name (Family Name of First Inventor)	Class	Sub Class	Filing Date (if appropriate)
	AR					
	BR					
	CR					
	DR					
	ER					
	FR					
	GR					
	HR					
	IR					
	JR					
	KR					
	LR					
	MR					
	NR					

FOREIGN PATENT DOCUMENTS

	Document Number	Date MM/YYYY	Country	Inventor Name	English Abstract		Translation Readily Available	
					Enclosed	No	Enclose	No
	OR							
	PR							
	QR							
	RR							
	SR							
	TR							
	UR							
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	WR							
	XR							

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RECEIVED

OTHER (Including in this order Author, Title, Periodical Name, Date, Pertinent Pages, etc.)

YR	T. Hamamoto et al., "well concentration: A Novel Scaling Limitation Factor derived from DRAM, Retention Time and Its Modeling" IEDM Tec. Dig., P915-918			
ZR				
AAR				
BBR				

Examiner

Date Considered:

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.